

PART OBSOLETE - CONTACT US



DDA (LO-R1) U

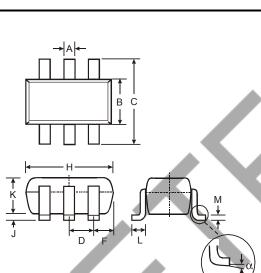
PNP PRE-BIASED DUAL TRANSISTOR

#### **Features**

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDC)
- Built-In Biasing Resistors
- Lead-Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

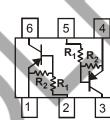
### Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
  Terminals: Finish Matte Tin Solderable per
- MIL-STD-202, Method 208
  Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: See Page 3
- Type Code: See Table Below
- Ordering Information: See Page 3
- Weight: 0.0058 grams (approximate)

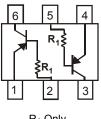


;	SOT-363	;					
Dim	Min Max						
Α	0.10	0.30					
в	1.15         1.35           2.00         2.20						
С	2.00	2.20					
D	0.65 N	ominal					
F	0.30 0.40						
Н	1.80	2.20					
J	— 0.10						
K	0.90 1.00						
L	0.25 0.40						
М	0.10 0.25						
α	0°	8°					
All Dim	ensions	in mm					

P/N	R1 (NOM)	R2 (NOM)	Type Code
DDA122LU	0.22K	10K	P81
DDA142JU	0.47K	10K	P82
DDA122TU	0.22K	OPEN	P83
DDA142TU	0.47K	OPEN	P84



 $R_1, R_2$ 





SCHEMATIC DIAGRAM

# Maximum Ratings NPN Section @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Supply Voltage (1) to (6) and (4) to (3)		Vcc	-50	V	
Input Voltage (1) to (2) and (4) to (5)	DDA122LU DDA142JU	V <sub>IN</sub>	+5 to -6 +5 to -6	V	
Input Voltage (1) to (2) and (4) to (5)	DDA122TU DDA142TU	V <sub>EBO (MAX)</sub>	-5	V	
Output Current	All	Ic	-100	mA	
Power Dissipation (Note 2)		Pd	200	mW	
Thermal Resistance, Junction to Ambient Air (N	lote 2)	$R_{ heta JA}$	625	°C/W	
Operating and Storage Temperature Range		Tj, T <sub>STG</sub>	-55 to +150	٥C	

Notes: 1. Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.

150mW per element must not be exceeded.

3. No purposefully added lead.

4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



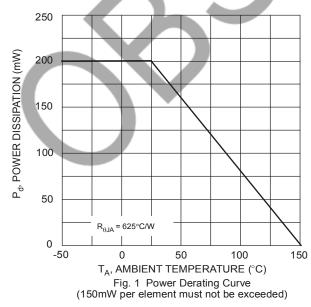
Electrical Characteristics @T <sub>A</sub> = 25°C unless otherwise specified R1, R2 Types									
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition		
Input Voltage	DDA122LU DDA142JU	V <sub>I(off)</sub>	-0.3 -0.3	_	_	V	V <sub>CC</sub> = -5V, I <sub>O</sub> = -100µA		
	DDA122LU DDA142JU	V <sub>l(on)</sub>	_	_	-2.0 -2.0	V	V <sub>O</sub> = -0.3V, I <sub>O</sub> = -20mA V <sub>O</sub> = -0.3V, I <sub>O</sub> = -20mA		
Output Voltage		V <sub>O(on)</sub>	_		-0.3V	V	I <sub>O</sub> /I <sub>I</sub> = -5mA/-0.25mA		
Input Current	DDA122LU DDA142JU	h	_	_	-28 -13	mA	V <sub>1</sub> = -5V		
Output Current		I <sub>O(off)</sub>			-0.5	μA	$V_{CC} = -50V, V_I = 0V$		
DC Current Gain	DDA122LU DDA142JU	GI	56 56		_	_	V <sub>O</sub> = -5V, I <sub>O</sub> = -10mA		
Gain-Bandwidth Product*		f⊤	_	200	_	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = -5mA, f = 100MHz		
* Transistor - For Reference Only									

Transistor - For Reference Only

Electrical Characteristics	@T <sub>A</sub> = 25°C unless otherwise specified	R1 Only Types
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	_					-	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage		BV <sub>CBO</sub>	-50	—		V	I <sub>C</sub> = -50μA
Collector-Emitter Breakdown Voltage		BV <sub>CEO</sub>	-40	_		V	I <sub>C</sub> = -1mA
Emitter-Base Breakdown Voltage DDA122TU DDA142TU		BV <sub>EBO</sub>	-5			V	I <sub>E</sub> = -50μA I <sub>E</sub> = -50μA
Collector Cutoff Current		I <sub>CBO</sub>	_	_	-0.5	μA	V <sub>CB</sub> = -50V
Emitter Cutoff Current DDA122TU DDA142TU		I <sub>EBO</sub>			-0.5 -0.5	μA	V <sub>EB</sub> = -4V
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>	_		-0.3	V	I <sub>C</sub> = -5mA, I <sub>B</sub> = -0.25mA
DC Current Transfer Ratio	DDA122TU DDA142TU	h <sub>FE</sub>	100 100	250 250	600 600		I <sub>C</sub> = -1mA, V <sub>CE</sub> = -5V
Gain-Bandwidth Product*		f⊤	_	200	_	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = 5mA, f = 100MHz

\* Transistor - For Reference Only





## Ordering Information (Note 6)

Device	Packaging	Shipping
DDA122LU-7-F	SOT-363	3000/Tape & Reel
DDA142JU-7-F	SOT-363	3000/Tape & Reel
DDA122TU-7-F	SOT-363	3000/Tape & Reel
DDA142TU-7-F	SOT-363	3000/Tape & Reel

Note:

6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# Marking Information



Pxx = Product Type Marking Code See Page 1 Diagrams YM = Date Code Marking Y = Year ex: I = 2021 M = Month ex: 9 = September

ate	Code	Key	

Date Code Key												
Year	20	)21	2022		2023	2	024	2025		2026	2	2027
Code		I	J		К		L	М		Ν		0
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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